INTERFACE CIRCUIT (RELAY AND LAMP-DRIVER)

- OPEN GROUND PROTECTION
- HIGH OUTPUT CURRENT
- ADJUSTABLE SHORT-CIRCUIT PROTECTION
- INTERNAL THERMAL PROTECTION WITH EXTERNAL RESET
- LARGE SUPPLY VOLTAGE RANGE
- ALARM OUTPUT
- INPUT VOLTAGE CAN BE HIGHER THAN V_{CC}
- OUTPUT VOLTAGE CAN BE LOWER THAN GROUND (V_{CC} V_O ≤ V_{CC}[max])



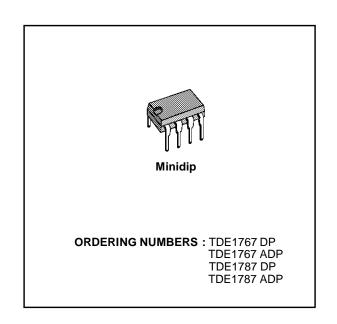
The TDE1767, A/TDE1787, A are a monolithic amplifiers designed for high current and high voltage applications, specifically to drive lamps, relays, stepping motors.

The devices are assentially blow-out proof. The output is prois protected from short-circuits with the positive supply or drive. In addition thermal shut down is provited to keep the IC from overheathing. If internal dissipation becomes too high, the driver will shut down to prevent excessive heating. The output stays null after the overheating is off, if the reset input is low. If high the output will alternatively switch-on and off until the overload is removed.

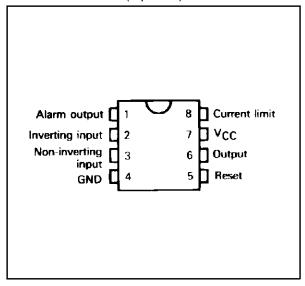
The devices operates over a wide range voltages from standard 15 V operational amplifier supplies to the single +6V or +48V used for industrial electric systems. Input voltages can be higher than in the Vcc.

An alarm output suitable for driving a LED is provited. This LED, normally on (if referred to ground), will die out or flash during an overload depending on the state of the reset input.

The output is low in open ground conditions.



PIN CONNECTION (top view)



THERMAL DATA

Symbol	Parameter	Value	Unit
R _{th (j - c)}	Maximum Junction-case Thermal Resistance	30	°C/W
R _{th (j - a)}	Maximum Junction-ambient Thermal Resistence	80	°C/W

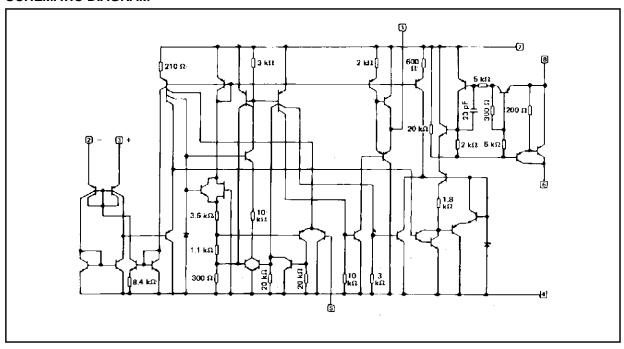
^{*} Devices bonded on a 40 cm2 glass-epoxy printed circuit 0.15 cm thick with 4 cm2 of copper.

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ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	TDE1767A/TDE1787A	TDE1767/TDE1787	Unit
Vcc	Supply Voltage	60	50	V
V _{ID}	Input Differential Voltage	60	50	V
Vı	Input Voltage	- 10 to + 60	- 10 to + 50	V
lo	Output Current	tput Current 1.3		Α
V _{I(reset)}	Reset Input Voltage	- 0.5 to + 60	- 0.5 to + 50	V
IOA	Alarm Output Current	- 10 to + 20	- 10 to + 20	mA
P _{tot}	Power Dissipation	Internally	mW	
T _{oper}	Operating Ambient Temperature Range	- 25 to + 85	- 25 to + 85	°C
T _{stg}	Storage Temperature Range	- 65 to + 150	- 65 to + 150	°C

SCHEMATIC DIAGRAM



EQUIVALENT SCHEMATIC

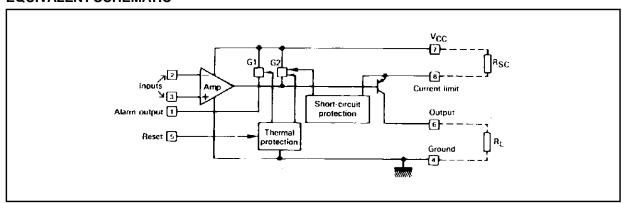
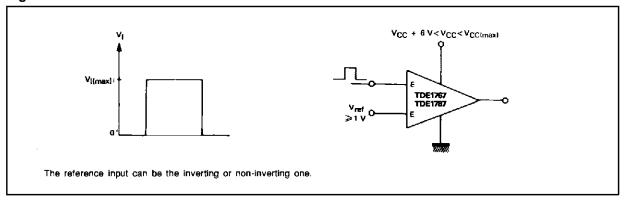


Figure 1.



ELECTRICAL CHARACTERISTICS (Unless otherwise specified)

TDE1767A: - 25 °C \leq T_{amb} \leq + 85 °C, + 6 V \leq V_{CC} \leq + 55 V, I₀ \leq 500 mA, T_i \leq + 150 °C **TDE1767**: $-25 \,^{\circ}\text{C} \le T_{amb} \le +85 \,^{\circ}\text{C}$, $+6 \,^{\circ}\text{V} \le V_{CC} \le +45 \,^{\circ}\text{V}$, $I_0 \le 500 \,^{\circ}\text{mA}$, $T_j \le +150 \,^{\circ}\text{C}$ **TDE1787A**: - 25 °C \leq T_{amb} \leq + 85 °C, + 6 V \leq V_{CC} \leq + 55 V, I₀ \leq 300 mA, T_j \leq + 150 °C **TDE1767A**: $-25 \,^{\circ}\text{C} \le T_{amb} \le +85 \,^{\circ}\text{C}$, $+6 \,^{\circ}\text{V} \le V_{CC} \le +45 \,^{\circ}\text{V}$, $I_{o} \le 300 \,^{\circ}\text{mA}$, $T_{i} \le +150 \,^{\circ}\text{C}$

Symbol	Parameter			Тур.	Max.	Unit
V _{IO}	Input Offset Voltage - (note 1)			2	50	mV
Icc	Power Supply Current (measured on pin 4)					mΑ
	Output High (T _{amb} = + 25 °C)			5.8	8	
	Output High ($V_{CC} = V_{CC(max)}$, $T_j = + 150 ^{\circ}C$)		-	5	7	
	Output Low (V _{CC} = V _{CC(max)} , T _{amb} = + 25 °C)			1.5	4	
I _{IB}	Input Bias Current			15	100	μΑ
V _{CM}	Common-mode Input Voltage Range	TDE1787A, TDE1767A TDE1787, TDE1767	1	-	60 45	V
Vı	Input Voltage Range (V _{ref} ≥ + 1 V) (figure 1, note 2)	TDE1787A, TDE1767A TDE1787, TDE1767	0 0		60 45	٧
I _{SC}	Short-circuit Output Current $(V_{CC} = + 35 \text{ V}, t = 10 \text{ ms})$					mA
	$R_{SC} = 0.22 \Omega$ $R_{SC} = 0.33 \Omega$	TDE1767A TDE1787A	-	700 380	- -	
V _{sense}	Output Limit Sense Voltage: $V_O = V_{CC} - 2 \text{ V}, t = 10 \text{ms}$ $(V_O = V_{CC} - 2 \text{ V})$: $V_O = 0 \text{ V}, t = 10 \text{ ms}$			150 140	170 165	mV
V _{O(sat)}	Output Saturation Voltage (output high $V_1^+ - V_1^- \ge 50$ mV, $R_{SC} = 0$, $V_{CC} = +30$ V)					V
	T _j = + 25°C	TDE1787A, TDE1767A	-	1	1.1	
	T . 450.00	TDE1787, TDE1767	-	1 1.1	1.2 1.2	
	T _j = + 150 °C	TDE1787A, TDE1767A TDE1787, TDE1767	-	1.1	1.3	
l _{OL}	Output Leakage Current (output low)			-	100	μА
l _Α	Available Alarm Output Current					mA
	Output Source Current (VAH = V _{CC} - 2.5 V) Output Slnk Current (in thermal shut-down) V _A = 1.4 V			-5 10	-	
I _{reset}	Reset Input Current			2	40	μΑ
V _{th (reset)}	Reset Threshold		-	1.4	-	V
-	Output Leakage Current (open ground)		-	10	-	μΑ

Notes: 1. The offset voltage given is the maximum value of different input voltage reguired to drive the output voltage whitin 2 V of the ground or the supply voltage.

2. Input voltage range is indipendent of the supply voltage.

Figure 2. PEAK SHORT-CIRCUIT vs LIMITING RESISTOR.

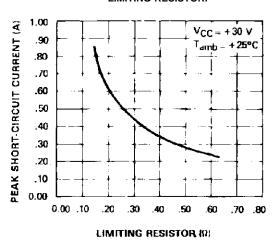


Figure 4. POWER SUPPLY CURRENT (pin 4).

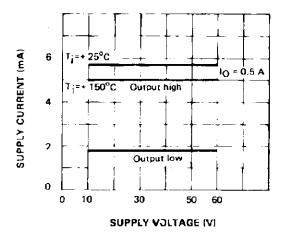


Figure 6. OUTPUT TRANSISTOR SAFE OPERATING AREA (pulsed)

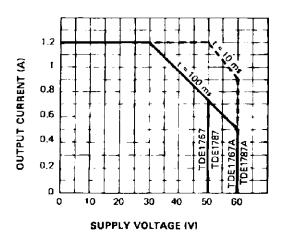


Figure 3. AVAILABLE OUTPUT CURRENT vs LIMITING RESISTOR.

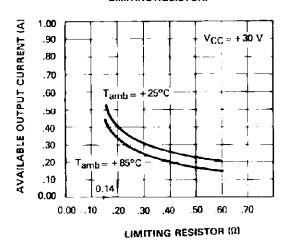


Fig.ure 5. OUTPUT SATURATION VOLTAGE vs OUTPUT CURRENT.

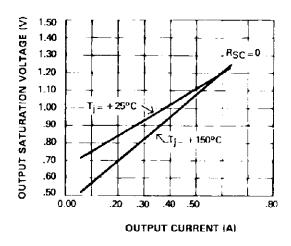
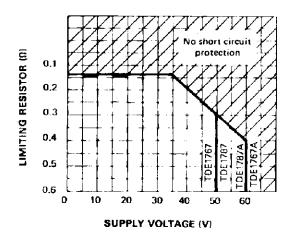
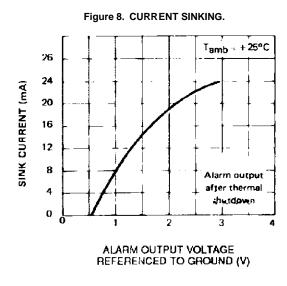
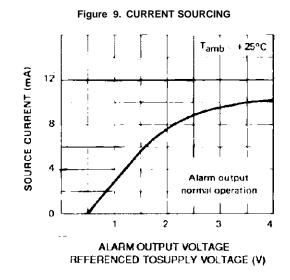


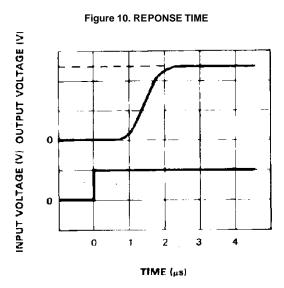
Figure 7. NORMAL OPERATING AREA (short circuit protected)



ALARM OUTPUT CAPABILITY CURRENT







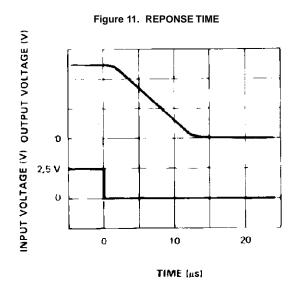
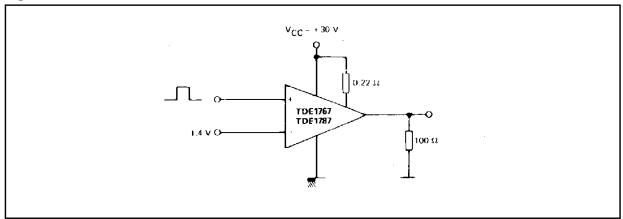


Figure 12: Test Circuit.



TYPICAL APPLICATION

Figure 13. Open Load Detection.

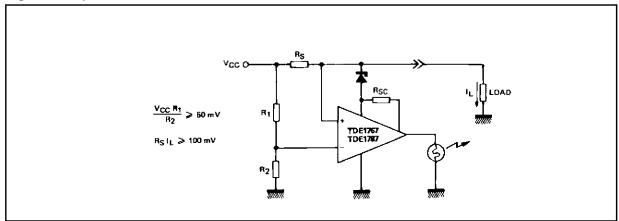


Figure 14. Driving Lamps, Relays, Etc...

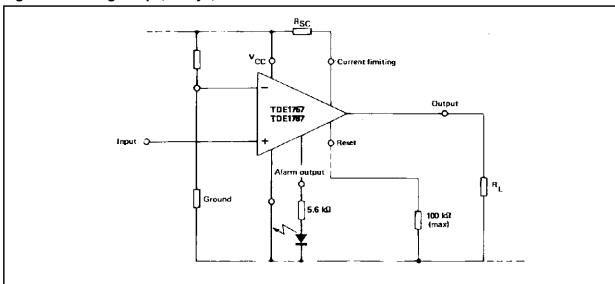


Figure 15. Common Reset.

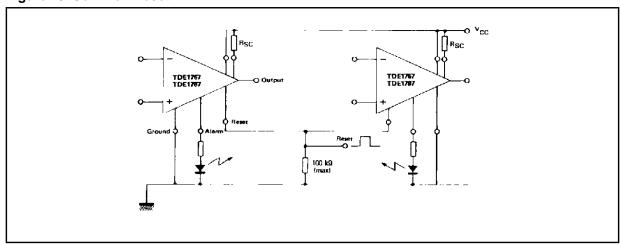
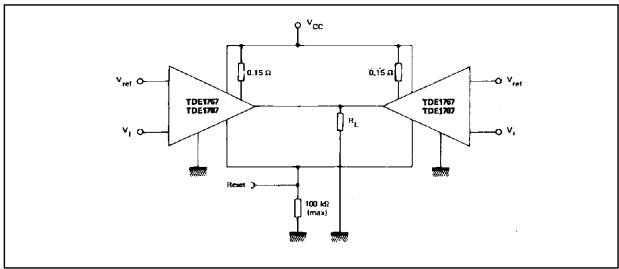


Figure 16. Parallel Driving of Loads Up to 1 A.



USING ALARM OUTPUT

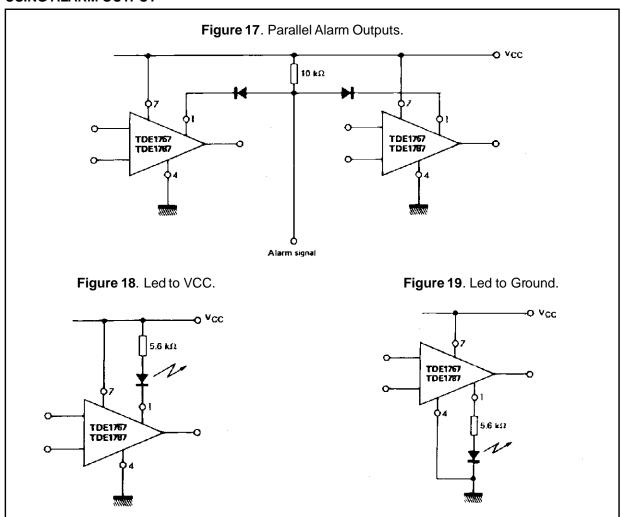


Figure 20. Interface between High oltage and Low Voltage System.

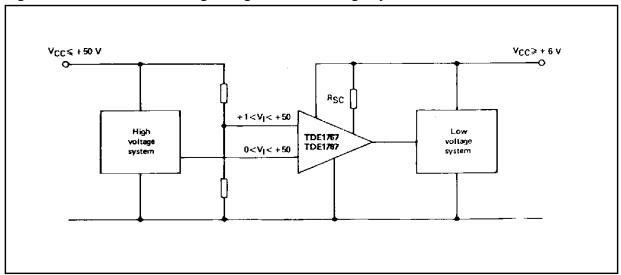
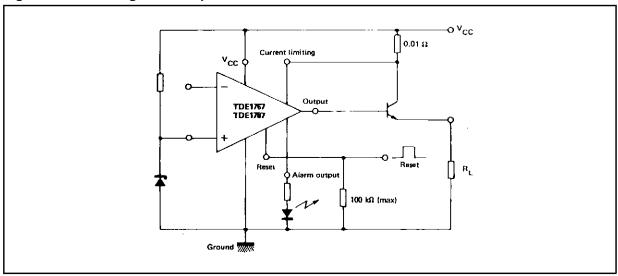
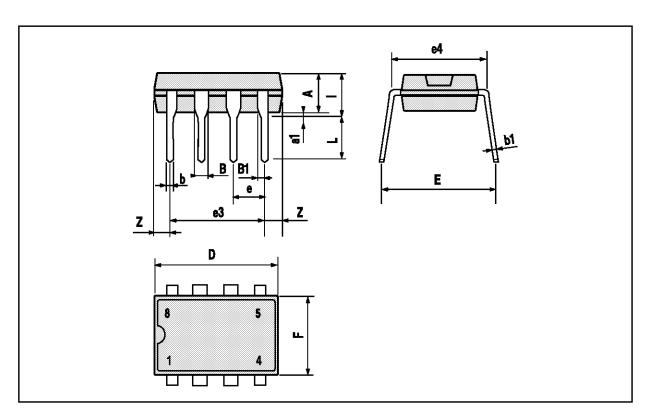


Figure 21. Increasing Current Up to 10 A.



MINIDIP PACKAGE MECHANICAL DATA

DIM.	mm			inch			
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.	
А		3.32			0.131		
a1	0.51			0.020			
В	1.15		1.65	0.045		0.065	
b	0.356		0.55	0.014		0.022	
b1	0.204		0.304	0.008		0.012	
D			10.92			0.430	
E	7.95		9.75	0.313		0.384	
е		2.54			0.100		
e3		7.62			0.300		
e4		7.62			0.300		
F			6.6			0.260	
l			5.08			0.200	
L	3.18		3.81	0.125		0.150	
Z			1.52			0.060	



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